## Quantum dot in the pseudogap K ondo state

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We investigate the transport properties of a (sm all) quantum dot connected to Ferm i liquid leads with a power-law density of states (DOS). Such a system, if experimentally realizable, will have interesting physical properties including: (i) non-saturating Coulomb blockade peak widths; (ii) a non-unitary Kondo peak symmetrically placed between Coulomb blockade peaks; (iii) an absence of conductance away from particle-hole symmetry at su ciently low temperatures; and (iv) evidence of a quantum critical point as a function of dot-lead hopping. These properties are compared and contrasted with one dimensional Luttinger systems exhibiting a power-law \tunneling-DOS".

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The realization[1] and veri cation[2] that singleim purity K ondo physics is experim entally accessible in quantum dot systems led to a renaissance of interest in this problem, inspiring works as diverse as investigations of non-equilibrium e ects [3] to the observation of manybody resonances such as the quantum corral[4]. The role of electron fractionalization has been important to descriptions of the fractional quantum Halle ect and spincharge separation in one dimension (1D). We study the transport properties of a (sm all) quantum dot connected to Fermi Liquid (FL) leads with a normalized power-law density of states (DOS) () =  $\frac{r+1}{2D}j_Df$ , D being the bandwidth, which allows us to probe exotic physics of the pseudogap K ondo m odel[5] at the nanoscale. This may allow for the rst m easurem ent of a K ondo state with a fractional phase shift of its conduction electrons [6, 7]. In contrast with the constant DOS case, odd Coulomb val-Leys no longer 11 in, so Coulom b blockade peaks (Cbps) are well separated from Kondo peaks due to an opacity to conductance introduced by particle-hole sym m etry (phs) breaking terms which completely change the nature of the strong coupling xed point[7]. Prelim inary results can be found in Ref. 8. Can such a power-law DOS be realized? One is naturally drawn towards materials with nodal quasiparticles (qps) along their Ferm i surfaces such as the d-wave high temperature cuprate superconductors (d-sc) or heavy ferm ion systems. The Kondo e ect we describe will not be measureable when r = 1 excluding imm ediately the former which exhibit a linear DOS along the nodal directions. However, it is reasonable to expect realizations of such ideas in the future.

When tunneling through a single-barrier, one of the main e ects of interactions in 1D Luttinger systems is to renormalize the tunneling-DOS (TDOS), which means the DOS to add an electron at an energy [9]: ()/jj^{1+1=g}, g is the well-known Luttinger exponent and g < 1 for repulsive interactions. A similar e ect can be obtained in the case of a mesoscopic conductor embedded in an electrical circuit with an ohmic resistance R. Indeed, by tunneling through a tunnel junction in the presence of an ohmic environment, in the linear re-

sponse regim e the theory predicts a conductance G (V) /  $\mathcal{Y} \mathcal{J}^{R=R_K}$ ,  $R_K = \frac{h}{e^2} = 25.8k$  being the quantum of resistance and V the bias voltage [10], which from Ferm i's golden rule  $G(V) / (V)^2$  m ight also be interpreted as a power-law TDOS ()/ $j_j^{R_i=R_K}$ . The mapping between these two problems has been addressed in Ref. 11 and explicitly proven recently in Ref. 12. Evidence for such a small power-law TDOS has been shown in dierent materials including small-capacitance junctions[13], (multiwall) nanotubes[14], and NbSe3 quantum wires[15]; the last two might nd description in terms of a multi-mode Luttinger theory without single-particle hopping between m odes[16]. By identifying () = (), one may wonder to what extent an analogy between the conductance of a FL with a power-law DOS and that of a 1D system with a power-law TDOS holds.

Here we focus on a quantum dot coupled to FL leads possessing a power-law DOS and compare and contrast with the situation of a quantum dot coupled to 1D leads.

Kane and Fisher[11] realized that, while a single im purity in a Luttinger liquid is localizing, a second barrier restores the ability of the system to conduct as  $T \,! \, 0$ , with  $G = gG_0$ , where the Luttinger parameter g < 1 for repulsive interactions and  $G_0$  is the unitary conductance  $\frac{2e^2}{h}$  . Furusakiand Nagaosa [17] extended this 1D work to extract the tem perature dependence of the height of the Cbps, found to grow as  $T^{\frac{1}{g}-2}$  at low temperatures, and the width of the peak, found to vanish as  $T^{\frac{1}{g}-1}$  (T, for long range interactions), with experim ental support [18]. Recently, Nazarov and Glazman [19] revisited the resonant tunneling problem in 1D to build a non-perturbative theory of the conductance valid in a broad region of T. The strong interaction  $\lim it (g = 1=2)$  has been treated to sim ilare ect[20]. We not the width of the C bps is at low T governed by the power of the DOS, vanishing as Tr. The height of the Cbps and K ondo peaks asymptote to  $G = G_0 \cos^2(\frac{r}{2})$  as T! 0. K ondo physics is predicted to occur when  $\bar{r} < \frac{1}{2}$  , the coupling J is su ciently large, and the number of dot electrons is odd, results di erent from 1D as detailed in Fig. 3. The potential for a tunable quantum critical point (qcp) and im plications at

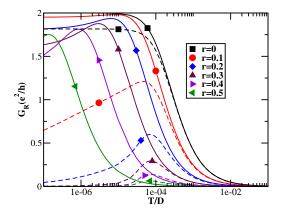


FIG. 1: Resonant tunneling conductance  $G_R$  vs. tem perature T for tunneling, t=0.01D. At  $_d=0$  (solid) all curves rise toward the unitary lim it before saturating at  $\frac{2e^2}{h}\cos^2{(\frac{r}{2})}$ . At sm all  $_d=10^{-4}D$  (dashed), curves vanish as  $T^{2r}$  as T:0.

asym m etric points are presented.

We consider the small dot, weak tunneling lim it in which the dot is a collection of discrete levels of average spacing E, of similar size as the charging energy, Ec  $(O(\frac{e^2}{2C}))$ , of the dot (e: electron charge; C: total capacitance of quantum dot). The energy to add/subtract an electron from the dot is E  $_{\text{c}}$  = E  $_{\text{tot}}$  (V  $_{\text{G}}$  ,n + 1) -E  $_{\text{tot}}$  (V  $_{\text{G}}$  , n) =  $(n + \frac{1}{2} - \frac{C_G V_G}{e}) \frac{e^2}{C}$ , where n is the initial (nal) num ber of electrons on the dot for + (-),  $E_{\text{tot}}$  is the total dot energy, and  $V_{\text{G}}$  is an external gate voltage coupled capacitively ( $C_G$ ) to the dot. For tem peratures satisfying  $E < T < E_c$ , the physics of the dot is dom inated by Coulomb blockade, whereas for T < E, single-level Coulom b blockade (E  $m in (E; E_c))$  occurs. Thus, for T < E , we can describe an e ective hopping across the dot in term s of a single im purity Anderson model[1],

$$H = \begin{cases} X \\ {}_{k}c_{k}^{y} c_{k} + (t_{k} c_{k}^{y} d + hx:) + {}_{d}n_{d} \\ + U n_{d\#}n_{d"}; \end{cases}$$
(1)

where  $c_k$  destroys a conduction electron of m omentum k, spin = ";#, from lead = L;R (L: left and R: right). M oreover,  $_d$  denotes the energy of the highest occupied level on the dot with occupancy  $n_d=d^yd$  and  $U=(E_c^++E_c^-)$  takes into account the C oulomb repulsion on the dot. K eep in m ind that here the conduction band is embodied by a power law DOS () =  $\frac{r+1}{2D}$   $\frac{1}{2D}$   $\frac{1}{2D}$   $\frac{1}{2}$ .

Resonant level lim it: The resonant lim it is reached by tuning the gate voltage  $V_{\rm G}$  such that the energy to add/subtract one electron obeys  $E_{\rm c}=0\,[1].$  In this case the e ective C oulomb interaction vanishes (U = 0) and the physics is that of a single level of energy  $_{\rm d}$ . To derive an expression for the conductance of the quantum dot system it is helpful to consider the current incident on,  $I_{\rm L}$ , and transmitted from ,  $I_{\rm R}$ , the dot. If we rst assume the dot is transparent then it is simple to

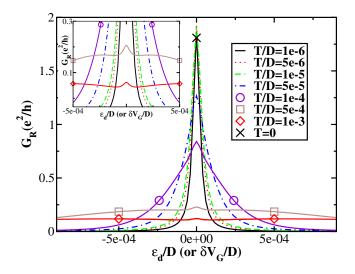


FIG. 2: Tem perature evolution of the conductance near the resonant point (  $_{\rm d}=$  0,  $V_{\rm G}=$  0) for r= 0.2, t= 0.01D . At high tem peratures unlike for r= 0, there is a clear m inim um (seen magni ed in the inset) as a function of  $V_{\rm G}$  and the maxim um of the conductance does not occur at resonance. Further lowering the tem perature, the conductance at  $_{\rm d}=$  0 grows as in Fig. 1, while the weight in the tails decreases.

write  $I_L=n_L\, ev=\frac{2e}{l}^P_{\quad k}\, f_L\, (\ _k)v=\frac{2e}{h}^{R_1}_{\quad l}\, d\,\, f_L\, (\ )$  and  $I=I_L$   $I_R$  . Here we assume an in nitesimal voltage drop from left to right across the dot and de ne  $n_{L\,(R\,)}=\frac{N_{L\,(R\,)}}{l}$  and  $f_{L\,(R\,)}(\ )$  as the density of particles and the Fermi function of the left (right) lead respectively; l the length of the lead; and  $v=\frac{1}{h}\frac{\theta}{\theta\,k}$  the drift velocity of the particles. In the rst step we replaced  $p(\ )$  d!  $p(\ )$  dk. This derivation is appropriate for FL leads (with electron-like quasiparticles). For non-unitary transmittance an additional factor occurs within the integral due to elastic scattering from the double barrier [21] to yield,

$$I = \frac{2e^{Z_{D}}}{h_{D}} d \frac{(f_{L}() f_{R}()) 4_{L}()_{R}()}{(d_{d} + ())^{2} + (f_{L}() + f_{R}())^{2}} : (2)$$

Here, we approximate  $t_k=t$ ,  $_L$ () and  $_R$ () are the widths of the quasilocal level associated with escape to respectively the left-hand and right-hand leads and () =  $_L$ () +  $_R$ () with () the corresponding real parts of the self-energies. These are dened as () =  $t^2$ ()[1] and () =  $t^2$ ()sgn() ( $(\frac{j}{D})^1$   $\frac{1}{r-1} {}_2F_1(1;\frac{1-r}{2};\frac{3-r}{2};(\frac{r}{D})^2)$ +  $tan(\frac{r}{2})$ ).[22] Below, we consider symmetric barriers where t=t which leads to  $_{L(R)}$ () =  $_0$   $\frac{j}{D}$  f with  $_0$ =  $\frac{(r+1)}{2D}t^2$ . The dierence between  $E_c$  and D may be quite large, as  $E_c$  1K, whereas D is the bandwidth of the electron leads. Using (2) we can calculate the bare conductance

$$G_{R} = \frac{dI}{dV} j_{V! 0} \text{ assum ing } L_{(R)} = \frac{eV}{2} \text{) to arrive at,}$$

$$G_{R} = \frac{2e^{2}}{h} \frac{^{2}(r)}{k_{B}T} \sum_{D} d \frac{j_{D}^{2} f()(1 - f())}{(d + ())^{2} + (2r)j_{D}^{2}};$$
(3)

where  $^{2}$  (r) =  $\frac{^{2}t^{4}(r+1)^{2}}{D^{2}(1+r)}$ , f(): Ferm i function at V = 0. It is straightforward to take the T = 0 lim it of this expression at resonance (  $_{d}$  = 0) to  $% _{R}=\frac{2e^{2}\cos ^{2}\left( \frac{-r}{2}\right) }{h}$ for r < 1;  $G_R = 0$  if r = 1. The conductance through a quantum dot can also be found [1] as  $G = G_0 \sin^2($ where () =  $\frac{1}{2}$  (1 rsgn ()) is known (for r < 1) to be the phase shift of the U = 0 Anderson model[6, 7]. The fractional phase shift can be interpreted as a decoupling of som e fraction, r, of spins of the conduction electrons at F. The temperature below which this saturation occurs is a decreasing function of r as shown in Fig. 1. Away from resonance (d f 0), at high temperatures the curves follow those of the resonant case, and for r = 0saturate to a non-zero value determ ined by the distance away from the resonant point with a Lorentzian lineshape of width  $_0$ . For r  $\theta$  0, the high tem perature curves again follow those at resonance but exhibit a maximum which gradually crosses over at very low temperatures to the power-law form  $T^{2r}$ , such that one is left at T = 0with function peaks as a function of d in place of the Lorentzian seen when r = 0.

We plot the resonant lineshapes as a function of V<sub>G</sub> as one decreases the temperature in Fig. 2 for the case r = 02.0 ne observes a distinctly non-Lorentzian shape to these curves at high temperatures where a doublepeak structure is evident{the wider peak exhibiting a pseudogap-like behavior as  $V_G$ ! 0 to e ectively shift the conductance maximum away from 0 as seen in the inset. As the tem perature decreases, the central peak grows to eventually dwarfthis outer structure. We stress that even this central peak does not have a Lorentzian line-width as can be seen by plotting the half-width vs. tem perature (not shown), which is seen for r = 0 to saturate to the value o and to vanish approximately as Tr at su ciently low tem peratures (all curves have approxim ately linear T-dependence at high tem peratures). Here, we still note some similarities with 1D systems with a TDOS[11, 17]; this suggests that in the case of two sym metric barriers in 1D, for certain ranges of and T, the model m ay be also rewritten in terms of decoupled elastic scattering amplitudes L(R) () =  $t^2$  () with () /  $j^{1+1=g}$  being the TDOS at each barrier, as em phasized in Ref.[19].

K ondo lim it: W e have seen that a power-law DOS enhances C oulom b blockade to such an extent that, at zero tem perature, Lorentzian lineshapes have been replaced by delta-function peaks about the resonant points where the energy to add or subtract an electron E $_{\rm c}^{+}$  vanishes. In regular quantum dots (r = 0), C oulom b valleys possessing an odd num ber of electrons allow certain spin- ip processes which at su ciently low energies T < E , grow

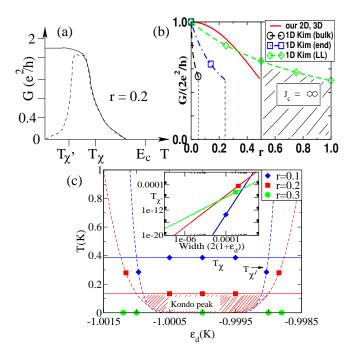


FIG.3: (a) Sketch of the conductance for r = 0.2 in a K ondo valley: (solid) at p-hs  $U = 2_d$  (on sets below T); (dashed) for V € 0 vanishes below T o. (b) The maximal height of the K ondo peak (at  $U = 2_d$ ) showing the  $\cos^2(-r)$  dependence and comparison with the 1D case at the one-channel K ondo xed point G =  $\frac{2e^2g}{h}$  [25] for: Luttinger liquids g = 1=(r+ 1); carbon nanotubes tunneling through the end [9]  $g_{end} =$ 1=(4r+1); the bulk [9]  $g_{bulk} = 1 + 4r$  $8r + 16r^2$ . (c) The  $V_{\text{G}}$  dependence of the crossover energy scales to enter the K ondo regim e if t = 31:6K , E  $_{\rm c}$  = 1K and D =  $10^3\,\rm K$  ; T: (solid); To: (dashed). The lled region labelled Kondo peak delineates the boundaries of the r = 0.2 K ondo e ect or the width of the conductance peak in the Kondo regime located in between the resonant peaks at  $_d$ = 0 and  $_d$ = 2K. N ote that, for the param eter choices indicated, T  $\,$  !  $\,$  0 for r > 0:31. (in set) a log log plot:  $T \circ vs$  width of the K ondo region at low T for di erent values of r (a -function at T = 0).

to eventually allow unitary conductance. Can this same physics be realized when the DOS of the conduction electrons in the leads follows a power law? To address this question we consider, for the same regime of T, the close vicinity of the point midway between two resonant peaks, with an odd number of electrons in the dot. This allows us to restrict the energy levels to a led level, with occupancy  $n_{\rm d}=d^yd$ ,  $E_{\rm c}=\frac{e^2}{2C}$  d below the Fermi energy and an unled level  $E_{\rm c}^+=\frac{e^2}{2C}$  U + d above.

In the lim it  $_{\rm d}$  (n odd dot energy), U +  $_{\rm d}$  (energy of 1st excitation) >> (  $_{\rm 0}$ , T ) we resort to the Schrie er-W ol transform ation to obtain the K ondo m odel[1]

$$H_{K} = \int_{k;k^{\circ};}^{X} J_{k;k^{\circ}} c_{k}^{Y} \frac{1}{2} c_{k^{\circ}} S + V_{k;k^{\circ}} c_{k}^{Y} c_{k^{\circ}} ; \qquad (4)$$

where S is the impurity spin of the level, the K ondo coupling  $J_{k;k^0}=2(\frac{1}{j_{\rm d}j}+\frac{1}{j_{\rm d}+j})t_kt_{k^0}$ , and the potential scat-

tering  $V_{k;k^0}=\frac{1}{2}\,(\frac{1}{j_d\,j}-\frac{1}{jJ+_d\,j})t_k\,t_{k^0}$  vanishes at the sym-m etric point  $U=2_d$ . The lead index has disappeared as only the symmetric combination of leads is coupled to the level through Eq.(1) [1]. For FL leads, it has been shown [1] that within the K ondo regime scattering through the impurity spin of the dot simply introduces a phase shift of the conduction electrons. Thus it is possible to map the strong coupling regime of the Anderson model to the U=0 resonant Anderson model. For a constant density of states in the lead (r=0), the strong coupling xed point of the K ondo model corresponds to a phase shift =2 so one recovers unitary conductance as T:0. Below, we treat two cases arising when  $r \in 0$  using knowledge of the pseudogap K ondo model[5, 6, 7].

For p-hs ( $V = V_{k;k} = 0$ ) when the dot-lead hybridization is su ciently large one can once more perform this mapping to the pseudogap U = 0 resonant Anderson m odel[7]. Hence, provided  $J = J_{k;k^0}$  is greater than a critical value  $J_c$ , as r decreases the conductance at the point sym m etrically placed between Cbps should exhibit a low tem perature rise in conductivity to reach  $G = G_R$ at T = 0. The value of  $J_c$  can be estimated following the poor man's scaling analysis of Ref. [5] and in  $\frac{2rD}{r+1} j_E^D f$  ( 0c  $\frac{rE_c}{4} j_E^D f$ ) for our case we nd J<sub>c</sub> small r. Numerical work in the D = E  $\lim it[7, 23]$ shows  $J_c$  ( oc) diverges at r = 0.5. Nodal qps of d-sc leads (r = 1) should not support conductance. As a function of the matrix elements governing the hopping between dot and leads a qcp exists. For  $J < J_c$ , the local m om ent is unscreened blocking transport through the quantum dot (G = 0). For  $J > J_c$  one enters[5] the K ondo partially screened regime below the K ondo scale E  $(\frac{J-J_c}{J})^{\frac{1}{r}}$  [5] leading to G =  $G_0 \cos^2(\frac{1}{2}r)$ . Close to p-hs (V & 0 or U & 2 d), we can imagine extending the applicability of the above form alism with the proviso that the potential scattering term is no longer forbidden. W ith V  $\upliese 0$ , the strong-coupling xed point of p-hs is no longer stable [7]. For 0 < r < r = 0.375, below a tem perature scale [23] T  $\circ$   $j_{\overline{k}}^{\underline{V}}$   $j_{\overline{k}}^{\underline{I}}$  T one ow s [24] to an asym m etric strong coupling xed point w ith entropy S = 0and phase shift[7] = sgn() yielding G = 0.A sum mary of our results, including the peak width at nite T is presented in Fig. 3; these are compared and contrasted with 1D results [25] where a one-or two-channel K ondo e ect can occur depending on the range of interactions (and p-hs or the relevance of the V term [26]).

To sum marize, we have considered the idea of a quantum dot sandwiched between FL leads with a DOS (or equivalently hopping matrix elements) vanishing as a power law at the Fermienergy. We recapture the low temperature dependence of the widths of the 1D Cbps (r=1+1=g), while their height reaches  $G=\frac{2e^2\cos^2(\frac{-1}{L})}{h}$  as T! 0. In contrast, K ondo physics drastically changes from the 1D case, as the phase shift varies continuously from  $=\frac{1}{2}$  to  $=\frac{1}{4}$  as the exponent r changes from

0 to 0.5. This is a signature of incomplete spin screening which coincides with a non-vanishing entropy [6, 7] S = 2rln2 (S (r = 0) = 0: fully screened spin; S (r = 1=2) = ln(2): free spin). As in 1D [25], p-h asymmetry matters leading to sharp peaks as a function of  $V_G$ . Observation of the disappearance of the K ondo signal as a function of the dot-lead hopping at a critical K ondo coupling gives strong support for an underlying qcp.

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